

OM SENI



AZ5725-01F

1-Line Bi-directional TVS Diode

Features

- Ultra small package: 1.0x0.6x0.5mm
- Ultra low capacitance: 10pF max
- Ultra low leakage: nA level
- Low operating voltage: $\pm 5V$
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30kV$
 - Contact discharge: $\pm 30kV$
 - IEC61000-4-5 (Lightning) 7A (8/20 μs)
- RoHS Compliant

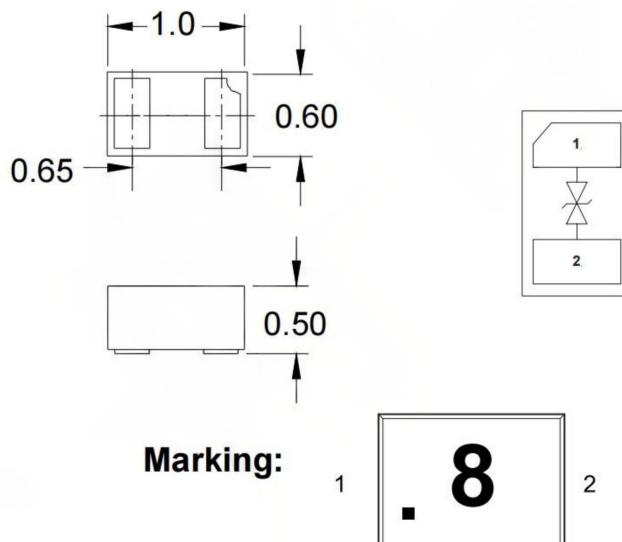
Mechanical Characteristics

- Package: DFN1006-2 (0402)
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Shipping Qty : 12000pcs/7Inch Tape & Reel

Applications

- Smart Phone and Tablet PC
- TV and Set Top Box
- Wearable Devices
- PDA

Dimensions and Pin Configuration

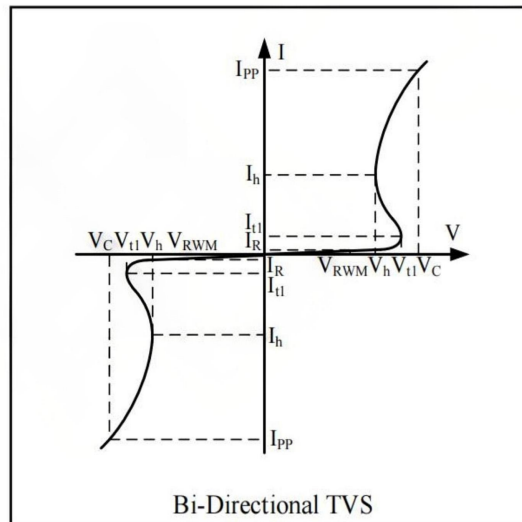


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Absolute Maximum Ratings ($T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	75	W
Peak Pulse Current (8/20 μs)	Ipp	7	A
ESD per IEC 61000-4-2 (Air)	VESD	± 30	kV
ESD per IEC 61000-4-2 (Contact)		± 30	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}\text{C}$

Symbol	Parameter
V_{RWM}	Nominal Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{tl}	Trigger Voltage
I_{tl}	Trigger Current @ V_{tl}
V_h	Holding Voltage
I_h	Holding Current @ V_h
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Maximum Peak Pulse Current
V_F	Forward Voltage @ I_F
C_{ESD}	Parasitic Capacitance



Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			5	V	
Breakdown Voltage	V_{BR}	5.6			V	$I_T = 1\text{mA}$
Reverse Holding Voltage	V_H	5.5			V	$I_H = 1\text{mA}$
Reverse Leakage Current	I_R			0.2	μA	$V_{RWM} = 5\text{V}$
Clamping Voltage	V_C			9	V	$I_{PP}=1\text{A}(8 \times 20\mu\text{s pulse})$
Clamping Voltage	V_C		15	17	V	$I_{PP}=7\text{A}(8 \times 20\mu\text{s pulse})$
Junction Capacitance	C_J		9	10	pF	$V_R = 0\text{V}, f = 1\text{MHz}$

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Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)

Fig1. 8/20 μs Pulse Waveform

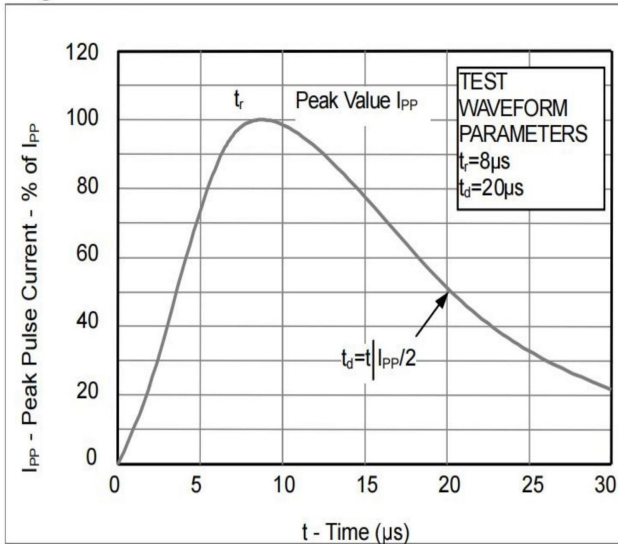


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

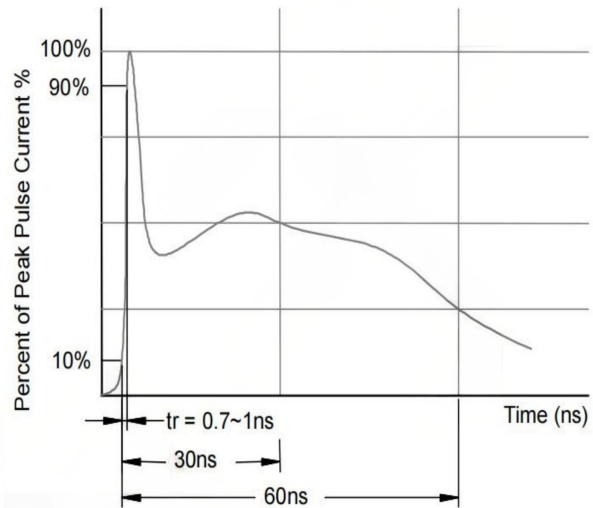
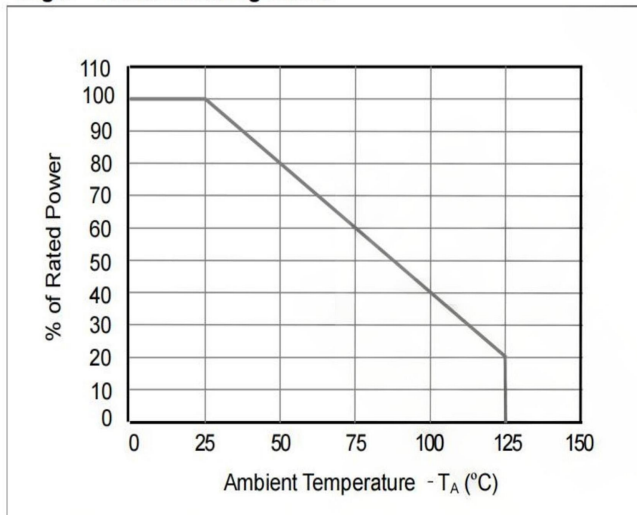


Fig3. Power Derating Curve



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Ordering Information

PREFERRED P/N	PACKAGE	SIZE(mm)	DELIVERY MODE	MPQ(PCS)
	DFN1006-2L	1.00×0.60×0.37	7" REEL	10,000

Recommended Soldering Conditions



Package Outline Dimensions (DFN1006-2L)

Symbol	Dimensions			
	Millimeters		Inches	
	Min	Max	Min	Max
A	0.950	1.050	0.037	0.041
B	0.550	0.650	0.022	0.026
C	0.350	0.450	0.014	0.018
D	0.550	0.650	0.022	0.026
D ₁	0.280	0.380	0.011	0.015
E	0.450	0.550	0.018	0.022
L	0.000	0.100	0.000	0.004

Suggested Pad Layout

Symbol	Dimensions			
	Millimeters		Inches	
	Min	Max	Min	Max
J	0.50	0.60	0.020	0.024
K	0.25	0.35	0.010	0.014
M	0.55	0.65	0.022	0.026